

/ Revised record

			8		

/ Descriptions

TO-220 N

N-CHANNEL MOSFET in a TO-220 Plastic Package.

/ Features

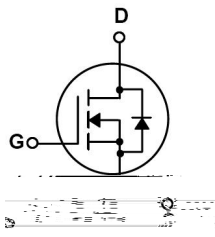
Ultra Low On-Resistance,fast switching.

/ Applications

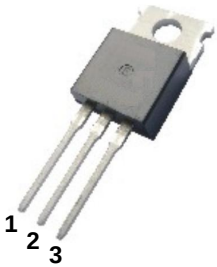
PFC

These devices are well suited for high efficient switched mode power supplies, Active power factor correction, electronic lamp ballast based on half bridge topology.

/ Equivalent Circuit



/ Pinning



PIN1 G

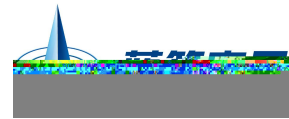
PIN 2 4 D

PIN 3 S

/ h_{FE} Classifications & Marking

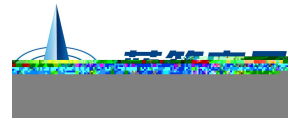
1

See Marking Instructions.



参数 Parameter		符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage		V _{DSS}	85	V
Drain Current		I _D (Tc=25℃)	70	A
Pulsed Drain Current		I _{DM}	245	A
Gate-Source Voltage		V _{GS}	±20	V
Single Pulsed Avalanche Energy L=0.5mH		E _{AS}	238	mJ
Avalanche Current		I _{AS}	75	A
Total Power Dissipation		P _D (Tc=25℃)	139	W
Junction and Storage Temperature Range		T _J ,T _{STG}	-55 to 150	℃
Thermal Resistance-Junction to Ambient	t ≤ 10s	R _{θJA}	15	℃/W
Thermal Resistance-Junction to Ambient	Steady-State		60	
Thermal Resistance-Junction to Case	Steady-State	R _{θJC}	0.9	

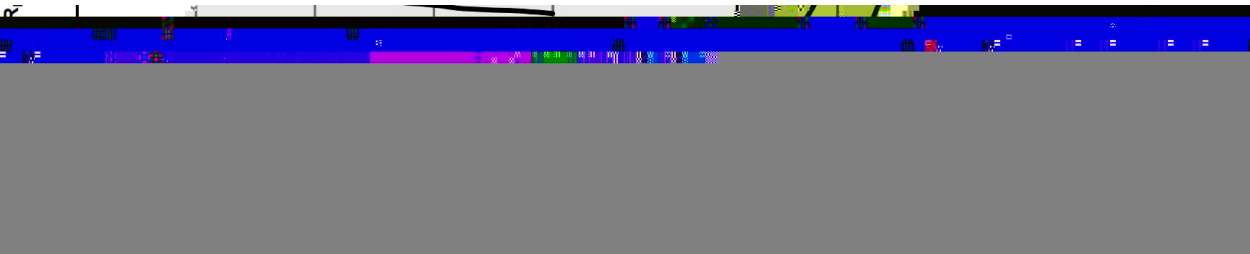
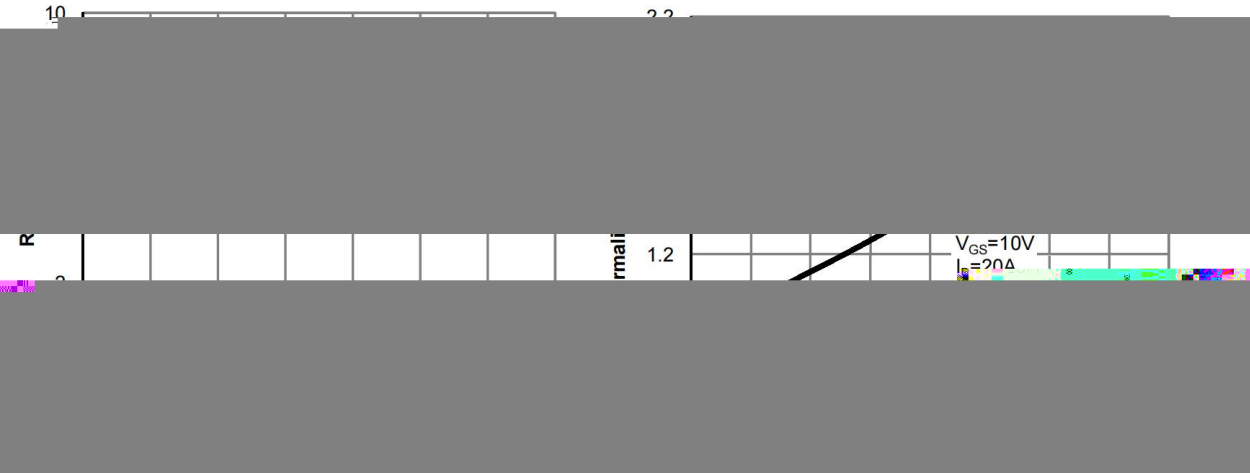
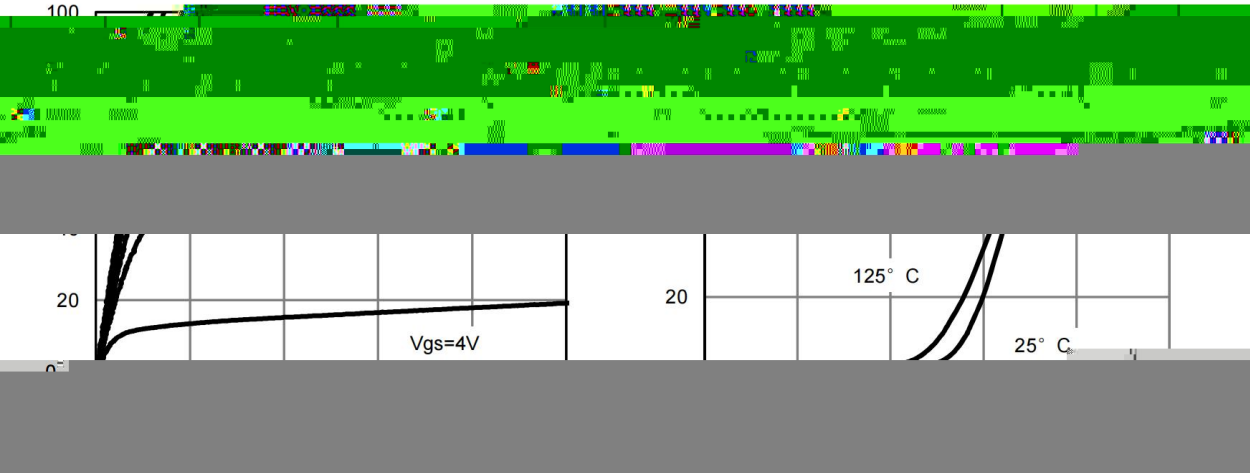
参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250\mu A$	85			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=85V$ $V_{GS}=0V$			1	μA
		$T_J=125^{\circ}C$			5	μA
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	2	3	4	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=70A$		4.5	5	m Ω
Forward On Voltage	V_{SD}	$V_{GS}=0V$ $I_S=1A$			1.2	V
Input Capacitance	C_{iss}	$V_{DS}=40V$ $V_{GS}=0V$ $f=1MHz$		2900		pF



/ Electrical Characteristics(Ta=25)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Gate resistance	R_g	$f=1\text{MHz}$		1.6		Ω
Total Gate Charge	$Q_g(10V)$	$V_{GS}=10V$ $V_{DS}=40V$ $I_D=20A$		44.5		nC
Gate Source Charge	Q_{gs}			12		
Gate Drain Charge	Q_{gd}			8		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=40V$ $R_L=2\Omega$ $R_{GEN}=3\Omega$		13.5		ns
Turn-On Rise Time	t_r			11		
Turn-Off Delay Time	$t_{d(off)}$			32		
Turn-Off Fall Time	t_f			11		

/ Electrical Characteristic Curve



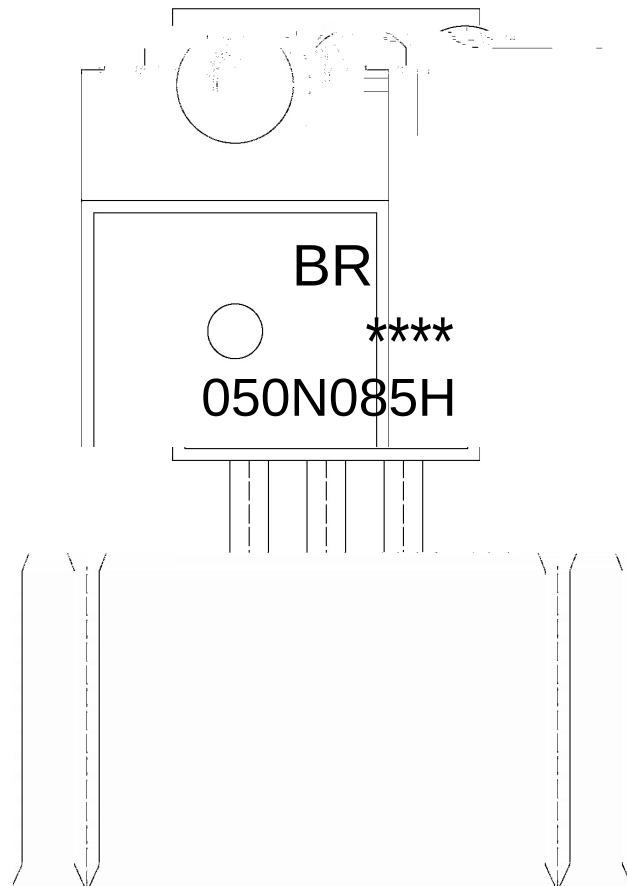
/ Electrical Characteristic Curve



BRCS050N085HRA

Rev.A Sep.-2021

DATA SHEET

/ Marking Instructions

说明：

BR： 为公司代码

050N085H： 为型号代码

****： 为生产批号代码，随生产批号变化。

Note:

BR: Company Code

050N085H: Product Type.

****: Lot No. Code, code change with Lot No.

()